

# Product Specification

XBLW AO4485

P-Channel Enhancement Mode MOSFET

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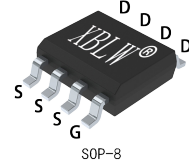


## Description

The AO4485 uses advanced trench technology to provide excellent RDS(ON) , low gate charge and operation with gate voltages as low as 2.5V. This device is suitable for use as a Battery protection or in other Switching application.

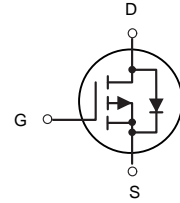
## General Features

- VDS = -40 V ID = -13A
- RDS(ON) < 19mΩ @ VGS= 10V



## Application

- Battery protection
- Load switch
- Uninterruptible power supply



P-Channel MOSFET

## Package Marking and Ordering Information

Product Model	Package Type	Marking	Packing	Packing Qty
XBLW AO4485	SOP-8	AO4485	Tape	3000Pcs/Reel

## Absolute Maximum Ratings (Tc=25°C unless otherwise noted )

Symbol	Parameter	Rating	Units
V <sub>DS</sub>	Drain-Source Voltage	- 40	V
V <sub>GS</sub>	Gate-Source Voltage	±20	V
I <sub>D</sub> @T <sub>A</sub> =25°C	Drain Current <sup>3</sup> , V <sub>GS</sub> @ 10V	-13	A
I <sub>DM</sub>	Pulsed Drain Current <sup>1</sup>	-52	A
P <sub>D</sub> @T <sub>A</sub> =25°C	Total Power Dissipation	3	W
T <sub>STG</sub>	Storage Temperature Range	-55 to 150	°C
T <sub>J</sub>	Operating Junction Temperature Range	-55 to 150	°C
R <sub>thj-a</sub>	Maximum Thermal Resistance, Junction-ambient <sup>3</sup>	41	°C/W

### Electrical Characteristics (T<sub>J</sub> = 25°C, unless otherwise noted)

Parameter	Symbol	Test Conditions	Min.	Typ.	Max.	Unit
<b>Static Characteristics</b>						
Drain-Source Breakdown Voltage	V <sub>(BR)DSS</sub>	V <sub>GS</sub> = 0V, I <sub>D</sub> = -250μA	-40	-	-	V
Gate-body Leakage current	I <sub>GSS</sub>	V <sub>DS</sub> = 0V, V <sub>GS</sub> = ±20V	-	-	±100	nA
Zero Gate Voltage Drain Current	T <sub>J</sub> =25°C	V <sub>DS</sub> = -40V, V <sub>GS</sub> = 0V	-	-	-1	μA
	T <sub>J</sub> =100°C		-	-	-100	
Gate-Threshold Voltage	V <sub>GS(th)</sub>	V <sub>DS</sub> = V <sub>GS</sub> , I <sub>D</sub> = -250μA	-1.0	-1.5	-2.2	V
Drain-Source On-Resistance <sup>4</sup>	R <sub>Ds(on)</sub>	V <sub>GS</sub> = -10V, I <sub>D</sub> = -10A	-	14.0	19	mΩ
		V <sub>GS</sub> = -4.5V, I <sub>D</sub> = -5 A	-	19.5	25	
Forward Transconductance <sup>4</sup>	g <sub>fs</sub>	V <sub>DS</sub> = -10V, I <sub>D</sub> = -10A	-	44	-	S
<b>Dynamic Characteristics<sup>5</sup></b>						
Input Capacitance	C <sub>iss</sub>	V <sub>DS</sub> = -20V, V <sub>GS</sub> = 0V, f = 1MHz	-	2525	-	pF
Output Capacitance	C <sub>oss</sub>		-	190	-	
Reverse Transfer Capacitance	C <sub>rss</sub>		-	172	-	
Gate Resistance	R <sub>g</sub>	f = 1MHz	-	10	-	Ω
<b>Switching Characteristics<sup>5</sup></b>						
Total Gate Charge	Q <sub>g</sub>	V <sub>GS</sub> = -10V, V <sub>DS</sub> = -20V, I <sub>D</sub> = -10A	-	35	-	nC
Gate-Source Charge	Q <sub>gs</sub>		-	5.5	-	
Gate-Drain Charge	Q <sub>gd</sub>		-	8	-	
Turn-On Delay Time	t <sub>d(on)</sub>	V <sub>GS</sub> = -10V, V <sub>DD</sub> = -20V, R <sub>G</sub> = 3Ω, I <sub>D</sub> = -10A	-	14.5	-	ns
Rise Time	t <sub>r</sub>		-	20.2	-	
Turn-Off Delay Time	t <sub>d(off)</sub>		-	32	-	
Fall Time	t <sub>f</sub>		-	10	-	
<b>Drain-Source Body Diode Characteristics</b>						
Diode Forward Voltage <sup>4</sup>	V <sub>SD</sub>	I <sub>S</sub> = -10A, V <sub>GS</sub> = 0V	-	-	-1.2	V
Continuous Source Current	T <sub>C</sub> =25°C	I <sub>S</sub>	-	-	-13	A

Note :

1. Repetitive rating, pulse width limited by junction temperature T<sub>J(MAX)</sub>=150°C.
2. The EAS data shows Max. rating . The test condition is V<sub>DD</sub>= -25V, V<sub>GS</sub>= -10V, L= 0.1mH, I<sub>AS</sub>= -34A.
3. The data tested by surface mounted on a 1 inch<sup>2</sup> FR-4 board with 2OZ copper, The value in any given application depends on the user's specific board design.
4. The data tested by pulsed , pulse width ≤ 300us , duty cycle ≤ 2%.
5. This value is guaranteed by design hence it is not included in the production test.

## Typical Characteristics

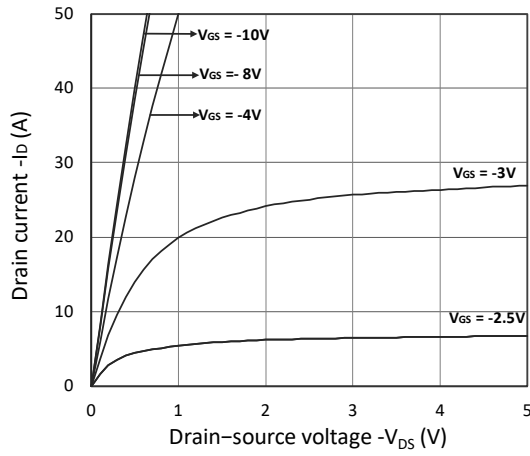


Figure 1. Output Characteristics

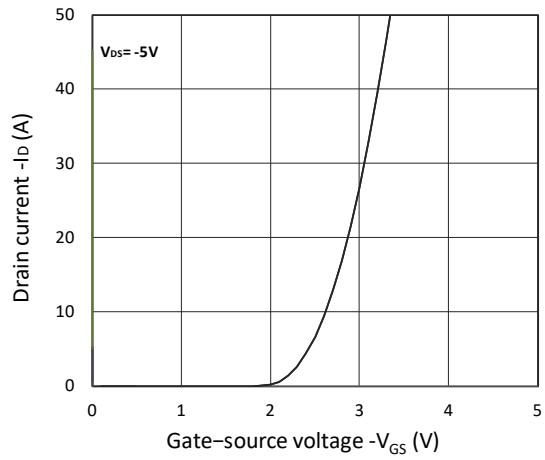


Figure 2. Transfer Characteristics

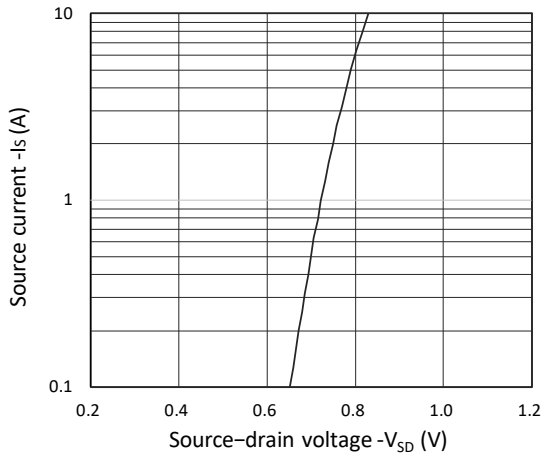


Figure 3. Forward Characteristics of Reverse

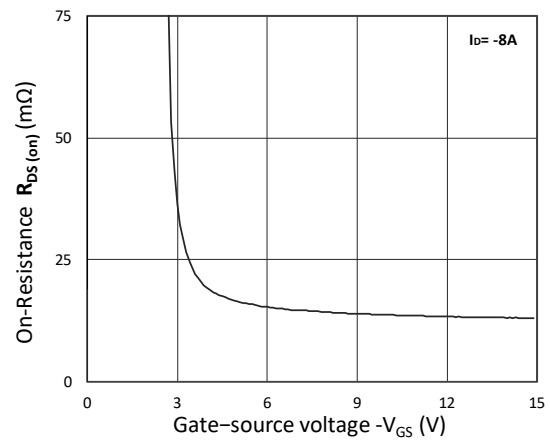


Figure 4.  $R_{DS(ON)}$  vs.  $V_{GS}$

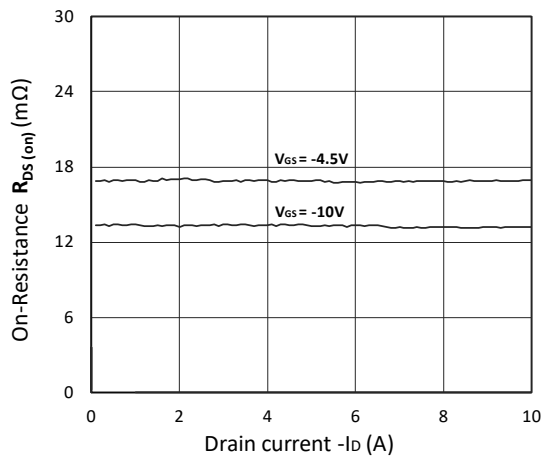


Figure 5.  $R_{DS(ON)}$  vs.  $I_D$

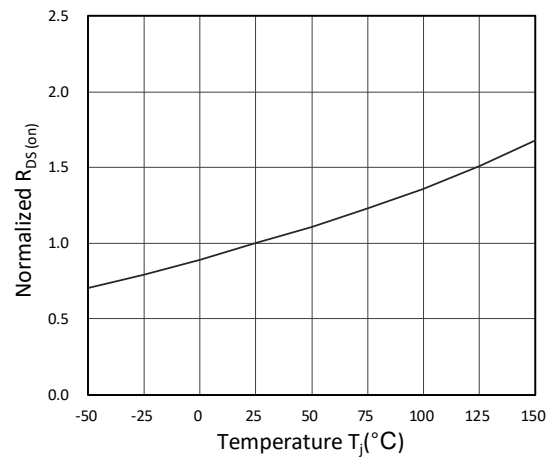


Figure 6. Normalized  $R_{DS(ON)}$  vs. Temperature

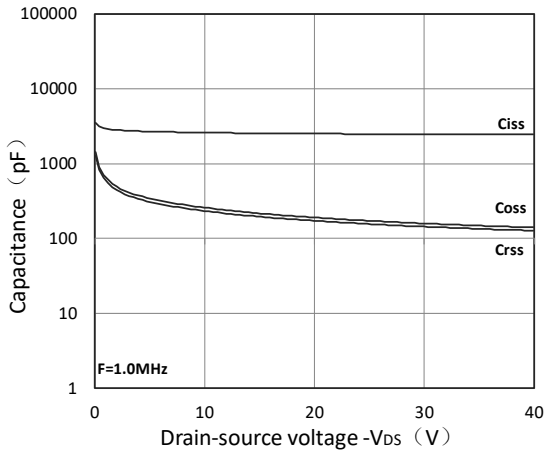


Figure 7. Capacitance Characteristics

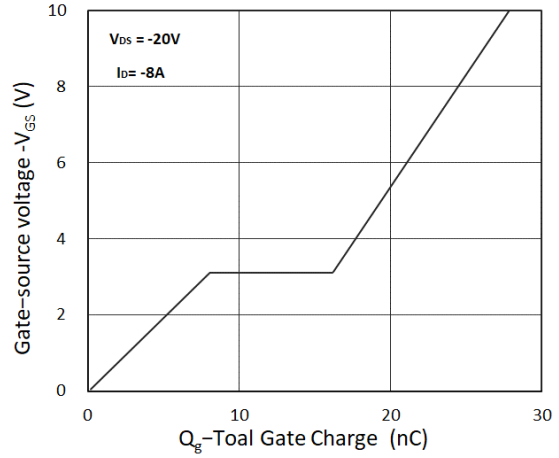


Figure 8. Gate Charge Characteristics

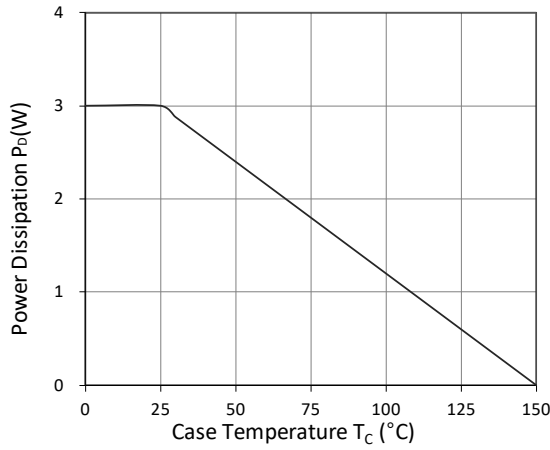


Figure 9. Power Dissipation

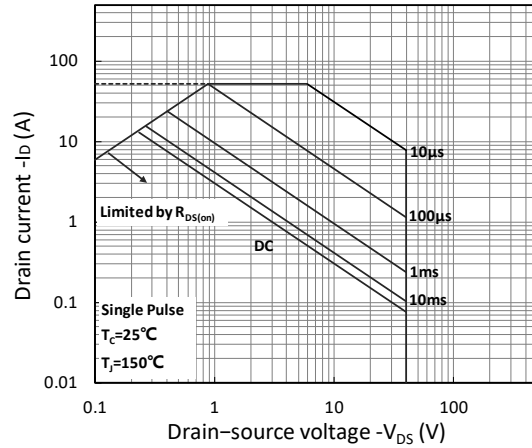


Figure 10. Safe Operating Area

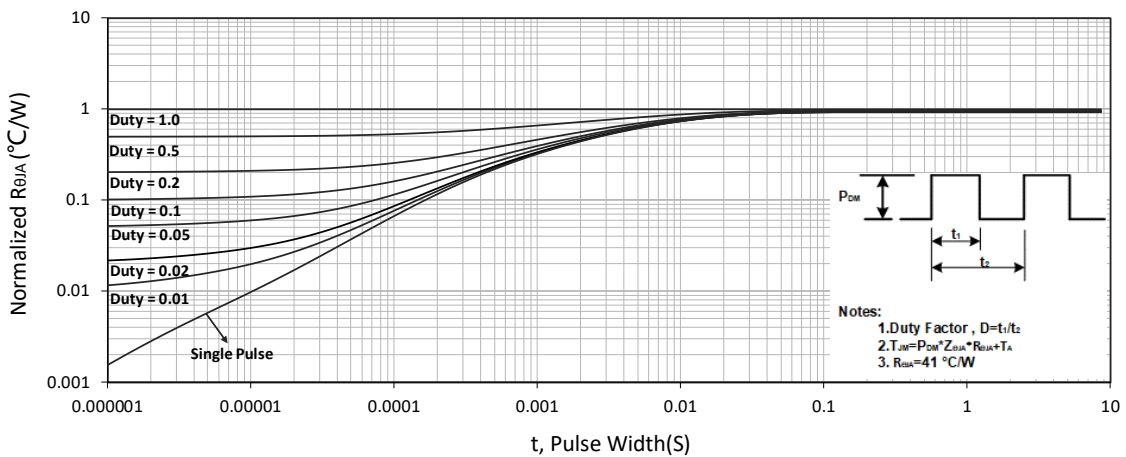


Figure 11. Normalized Maximum Transient Thermal Impedance

### Test Circuit

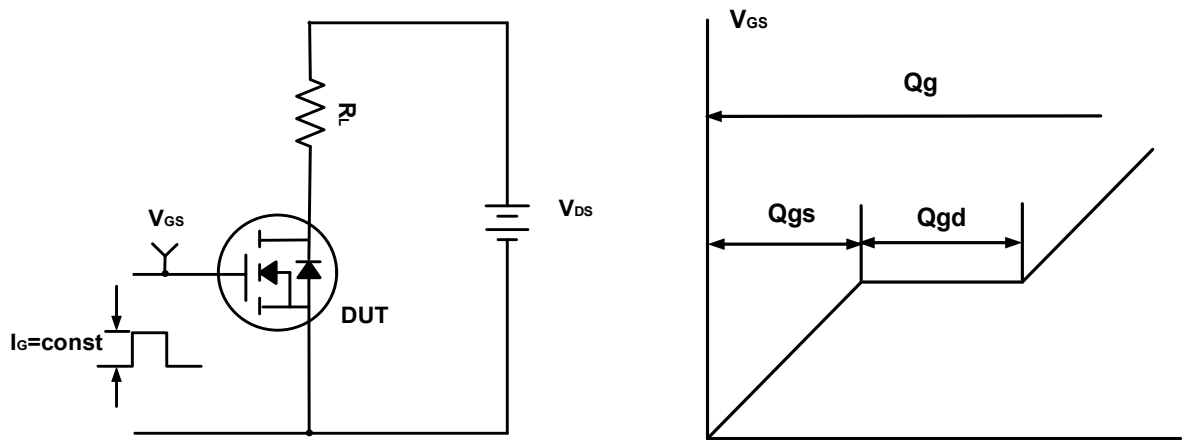


Figure A. Gate Charge Test Circuit & Waveforms

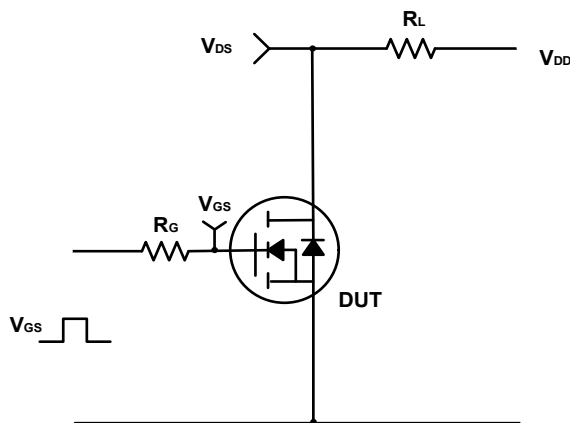


Figure B. Switching Test Circuit & Waveforms

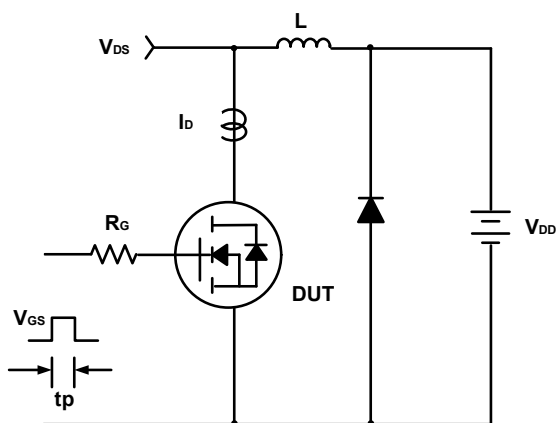
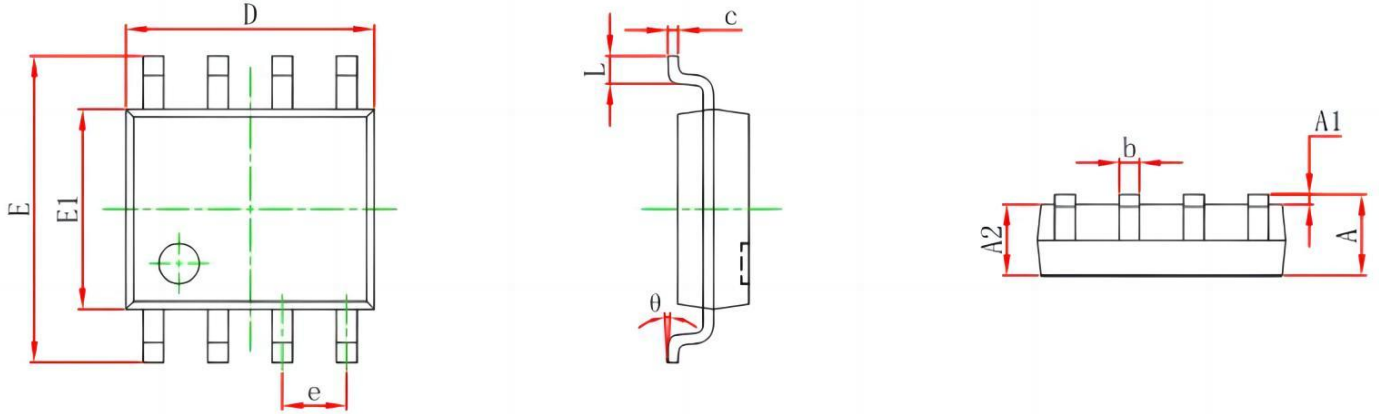


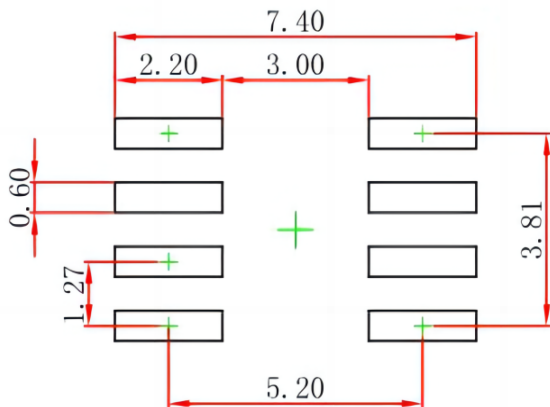
Figure C. Unclamped Inductive Switching Circuit & Waveforms

## Package Outline Dimensions

### SOP-8



Symbol	Dimensions In Millimeters		Dimensions In Inches	
	Min	Max	Min	Max
A	1.350	1.750	0.053	0.069
A1	0.100	0.250	0.004	0.010
A2	1.350	1.550	0.053	0.061
b	0.330	0.510	0.013	0.020
c	0.170	0.250	0.007	0.010
D	4.800	5.000	0.189	0.197
e	1.270 (BSC)		0.050 (BSC)	
E	5.800	6.200	0.228	0.244
E1	3.800	4.000	0.150	0.157
L	0.400	1.270	0.016	0.050
θ	0°	8°	0°	8°



**Note:**

1. Controlling dimension: In millimeters.
2. General tolerance:  $\pm 0.05\text{mm}$ .
3. The pad layout is for reference purposes only.

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